

40V PNP HIGH GAIN LOW SATURATION MEDIUM POWER TRANSISTOR

Description

This bipolar junction transistor (BJT) is designed to meet the stringent requirement of automotive applications.

Features

- $BV_{CEO} > -40V$
- $I_C = -5.5A$ Continuous Collector Current
- $I_{CM} = -15A$ Peak Pulse Current
- Very Low Saturation Voltage $V_{CE(SAT)} < -60mV$ max @ $-1A$
- $R_{SAT} = 29m\Omega$ @ $-5.5A$ for Low Equivalent On-Resistance
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

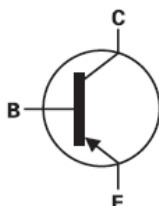
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 Ⓔ③
- Weight: 0.05 grams (Approximate)

Applications

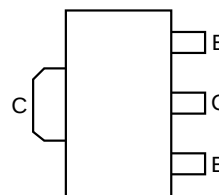
- DC-DC Converters
- MOSFET Gate Drivers
- Charging Circuits
- Power Switches
- Motor Control

SOT89


Top View



Device Schematic



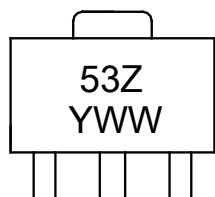
Pin-Out Top View

Ordering Information (Notes 4 and 5)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP2009ZQTA	53Z	7	12	1000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q10x qualified and are PPAP capable. Refer to <https://www.diodes.com/quality/>.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT89


53Z = Product Type Marking Code
 YWW = Date Code Marking
 Y = Last digit of year (ex: 8 = 2018)
 WW = Week code (01 – 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Base Voltage	V _{CBS}	-50	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-5.5	A
Peak Pulse Current	I _{CM}	-15	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

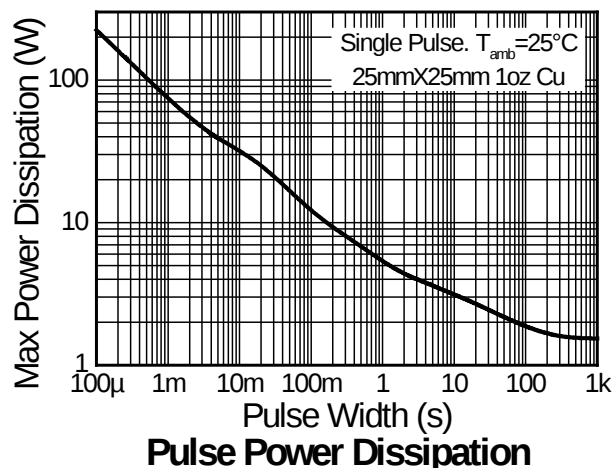
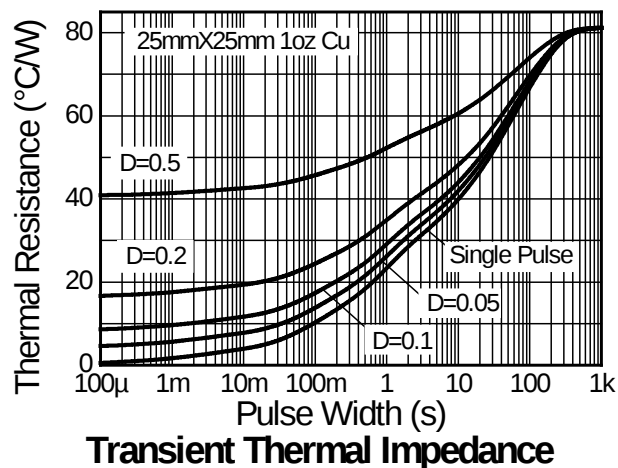
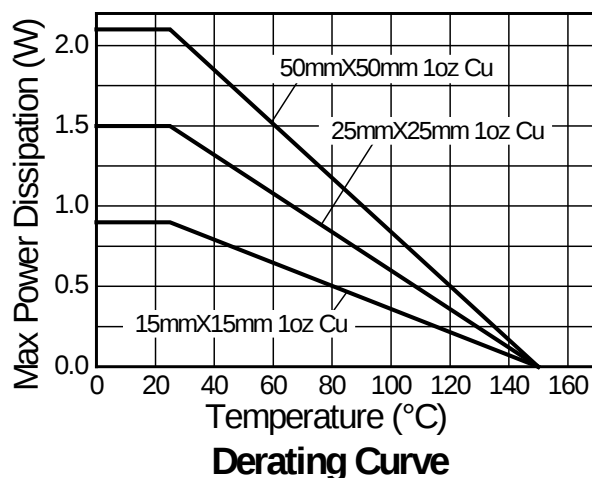
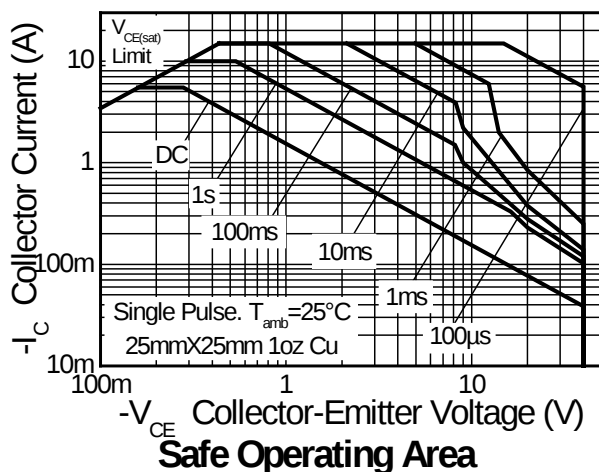
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P _D	0.9	W mW/°C
		7.2	
		1.5	
		12	
		2.1	
Thermal Resistance, Junction to Ambient	R _{θJA}	16.8	°C/W
		3	
		24	
		139	
		83	
Operating and Storage Temperature Range	T _J , T _{STG}	60	°C
		42	
		-55 to +150	

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	C

- Notes:
6. For a device mounted with the collector lead on 15mm × 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in steady-state.
 7. Same as Note 6, except the device is mounted on 25mm × 25mm 1oz copper.
 8. Same as Note 6, except the device is mounted on 50mm × 50mm 1oz copper.
 9. Same as Note 6, except the device is mounted on 25mm × 25mm measured at t<5 secs.
 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

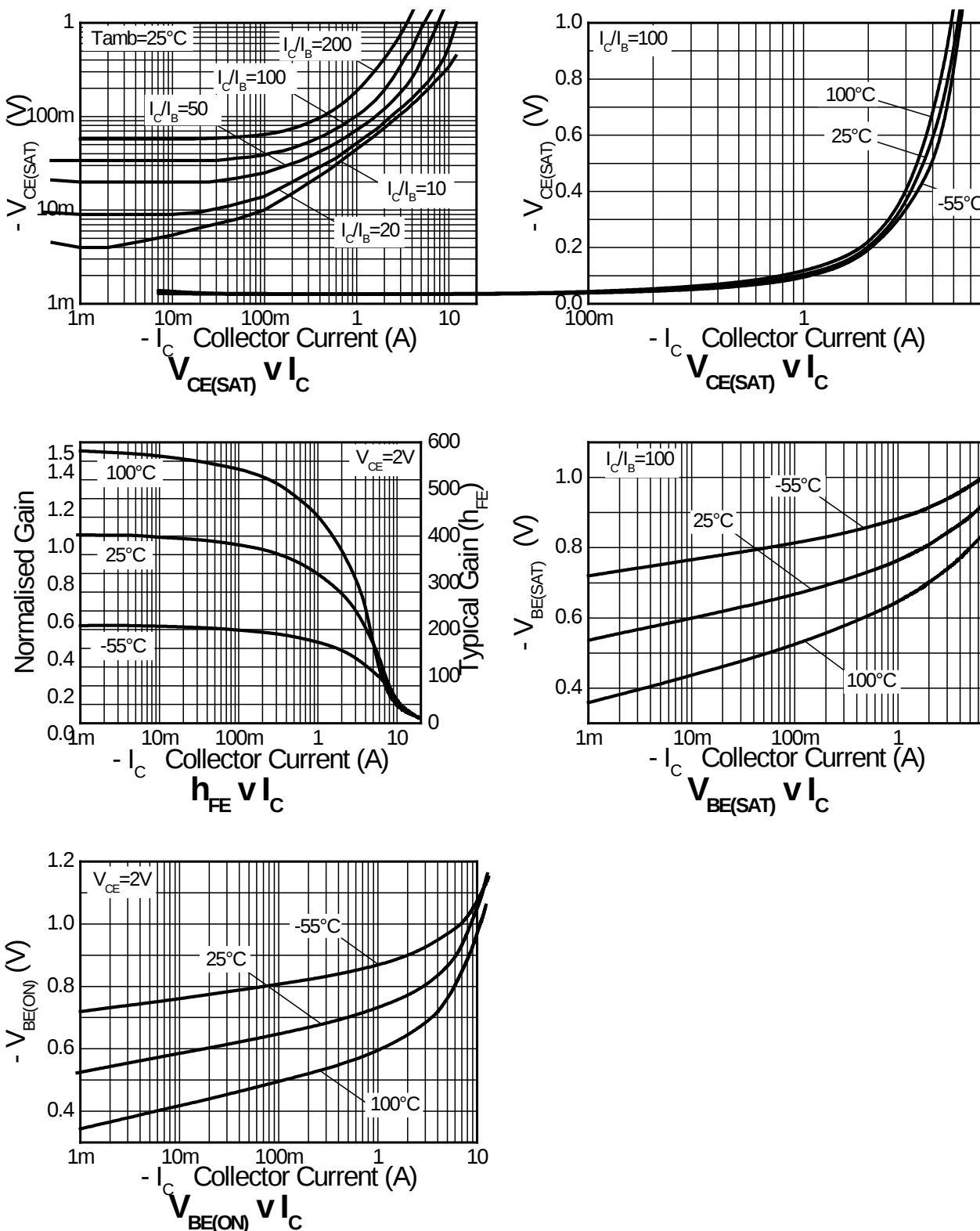


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	-90	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CER}	-50	-90	—	V	I _C = -1μA, R _B ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-40	-58	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7.5	-8.3	—	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	—	< -1	-20	nA	V _{CB} = -40V
Collector Cutoff Current	I _{CES}	—	< -1	-20	nA	V _{CB} = -32V
Emitter Cutoff Current	I _{EBO}	—	< -1	-20	nA	V _{EB} = -6V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(SAT)}	—	-15 -44 -50 -120 -70 -125 -130 -162	-30 -60 -70 -165 -80 -175 -175 -185	mV	I _C = -0.1A, I _B = -10mA I _C = -1A, I _B = -100mA I _C = -1A, I _B = -50mA I _C = -1A, I _B = -10mA I _C = -2A, I _B = -200mA I _C = -2A, I _B = -40mA I _C = -3.5A, I _B = -175mA I _C = -5.5A, I _B = -550mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(SAT)}	—	-820 -1000	-900 -1075	mV	I _C = -2A, I _B = -40mA I _C = -5.5A, I _B = -550mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(ON)}	—	-778 -869	-850 -950	mV	I _C = -2A, V _{CE} = -2V I _C = -5.5A, V _{CE} = -2V
DC Current Gain (Note 11)	h _{FE}	200 200 170 110	390 350 290 175	550	—	I _C = -10mA, V _{CE} = -2V I _C = -0.5A, V _{CE} = -2V I _C = -2A, V _{CE} = -2V I _C = -5.5A, V _{CE} = -2V
Transition Frequency	f _T	—	152	—	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Output Capacitance (Note 11)	C _{OBO}	—	53	—	pF	V _{CB} = -10V, f = 1MHz
Switching Times	t _d	—	18	—	ns	V _{CC} = -10V, I _C = -1A, I _{B1} = -I _{B2} = -100mA
	t _r	—	17	—		
	t _s	—	325	—		
	t _f	—	60	—		
Switching Times	t _d	—	55	—	ns	V _{CC} = -30V, I _C = -2A, I _{B1} = -I _{B2} = -20mA
	t _r	—	107	—		
	t _s	—	264	—		
	t _f	—	103	—		

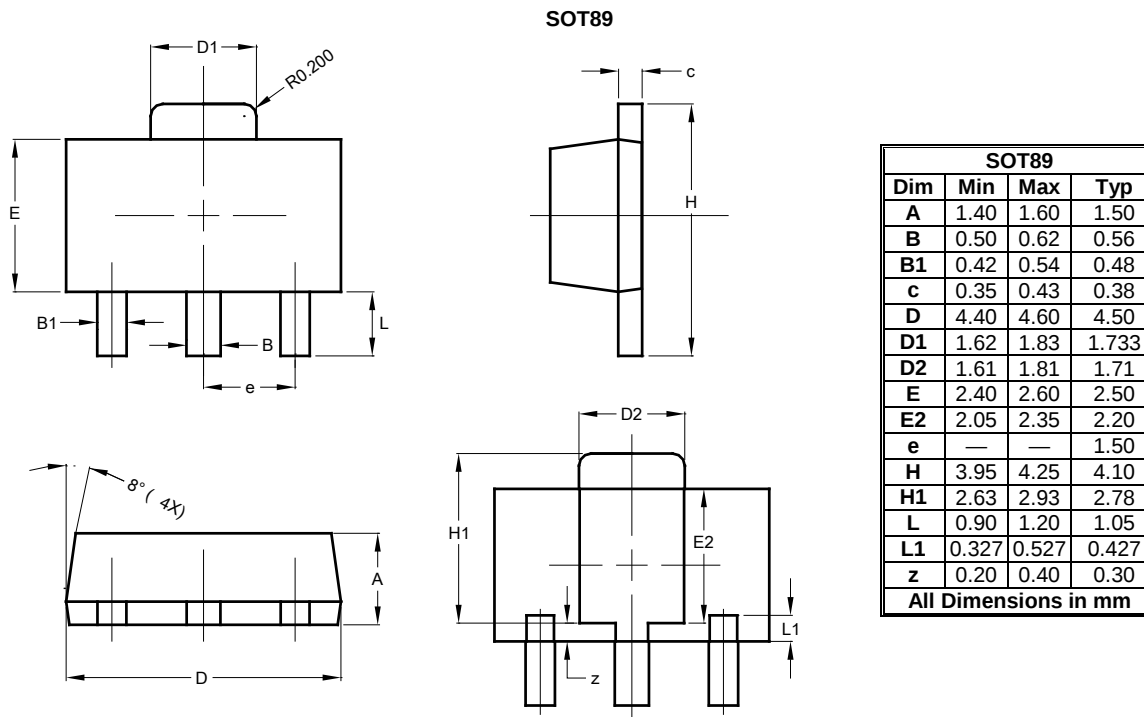
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



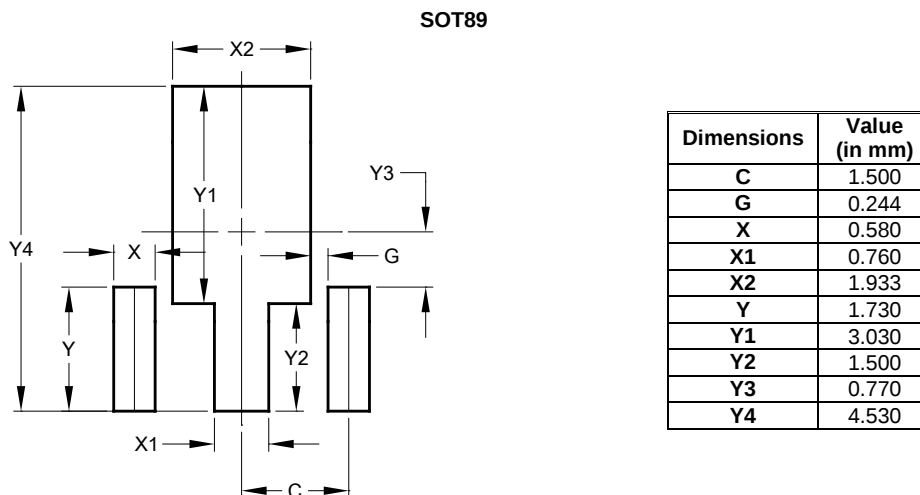
Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2018, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated:](#)

[ZXTP2009ZQTA](#)